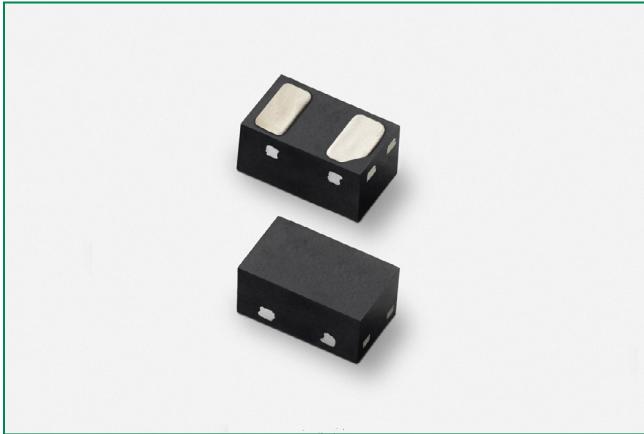


**SP1212****12A Discrete Unidirectional TVS Diode****OBSOLETE** DATE: 9/30/2021 PCN/ECN# ESU270-62  
REPLACED BY: SP1250-01ETG**Description**

The SP1212 unidirectional TVS is fabricated in a proprietary silicon avalanche technology. These diodes provide a high ESD (electrostatic discharge) protection level for electronic equipment. The SP1212 TVS can safely absorb repetitive ESD strikes of  $\pm 30$  kV (contact and air discharge as defined in IEC 61000-4-2) without any performance degradation. Additionally, each TVS can safely dissipate a 12A 8/20 surge event as defined in IEC 61000-4-5 2nd Edition.

**Features & Benefits**

- ESD, IEC 61000-4-2,  $\pm 30$ kV contact,  $\pm 30$ kV air
- EFT, IEC 61000-4-4, 40A (5/50ns)
- Lightning, 12A (8/20 $\mu$ s as defined in IEC 61000-4-5 2nd edition)
- AEC-Q101 qualified
- Lead free and RoHS compliant
- Moisture Sensitivity Level(MSL -1)

**Additional Information**

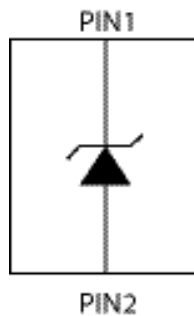
Resources



Accessories



Samples

**Pinout and Functional Block Diagram****Applications**

- Switches / Buttons
- Test Equipment / Instrumentation
- Point-of-Sale Terminals
- Medical Equipment
- Notebooks / Desktops / Servers
- Computer Peripherals
- Battery

Life Support Note:

**Not Intended for Use in Life Support or Life Saving Applications**

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

# SP1212

## 12A Discrete Unidirectional TVS Diode

### Absolute Maximum Ratings

Symbol	Parameter	Value	Units
$P_{pk}$	Peak Pulse Power ( $t_p=8/20\mu s$ )	250	W
$T_{OP}$	Operating Temperature	-40 to 125	$^{\circ}C$
$T_{STOR}$	Storage Temperature	-55 to 150	$^{\circ}C$

**Caution:** Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the component. This is a stress only rating and operation of the component at these or any other conditions above those indicated in the operational sections of this specification is not implied.

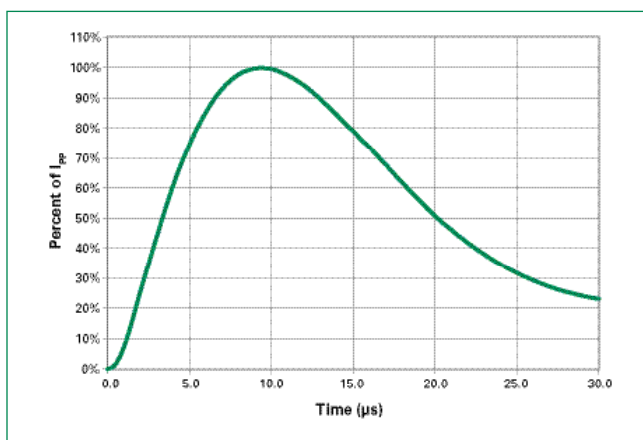
### Electrical Characteristics ( $T_{OP}=25^{\circ}C$ )

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	$V_{RWM}$	$I_R=1\mu A$			5.0	V
Breakdown Voltage	$V_{BR}$	$I_R=1mA$		7.0		V
Reverse Leakage Current	$I_{LEAK}$	$V_R=5V$		0.1	0.5	$\mu A$
Clamp Voltage <sup>1</sup>	$V_C$	$I_{PP}=1A, t_p=8/20\mu s$		7.5		V
		$I_{PP}=12A, t_p=8/20\mu s$		9.7		V
Dynamic Resistance <sup>2</sup>	$R_{DYN}$	TLP, $t_p=100ns$ , I/O to GND		0.33		$\Omega$
Peak Pulse Current	$I_{PP}$	$t_p=8/20\mu s$		12		A
ESD Withstand Voltage <sup>1</sup>	$V_{ESD}$	IEC 61000-4-2 (Contact Discharge)	$\pm 30$			kV
		IEC 61000-4-2 (Air Discharge)	$\pm 30$			kV
Diode Capacitance <sup>1</sup>	$C_{I/O-GND}$	Reverse Bias=0V, $f=1MHz$		290		pF

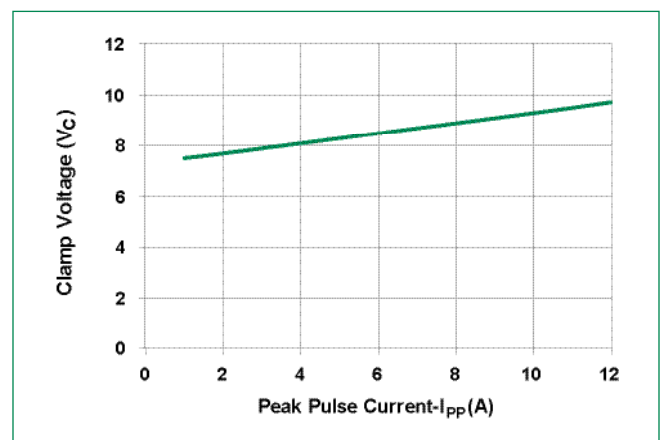
**Note:**

- Parameter is guaranteed by design and/or component characterization.
- Transmission Line Pulse (TLP) with 100ns width, 2ns rise time, and average window  $t_1=70ns$  to  $t_2=90ns$

### 8/20 $\mu s$ Pulse Waveform



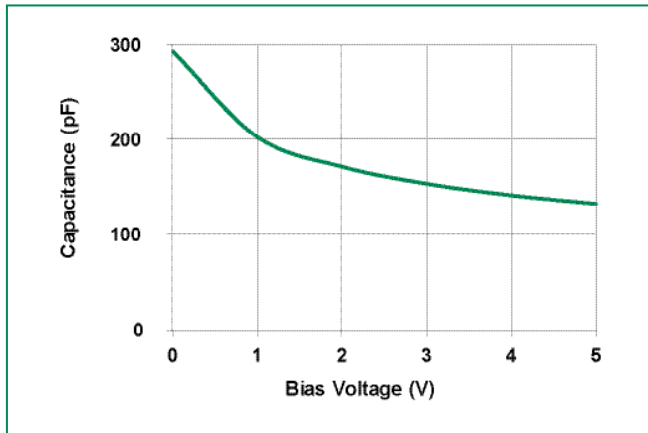
### Clamping Voltage vs IPP for 8/20 $\mu s$ waveshape



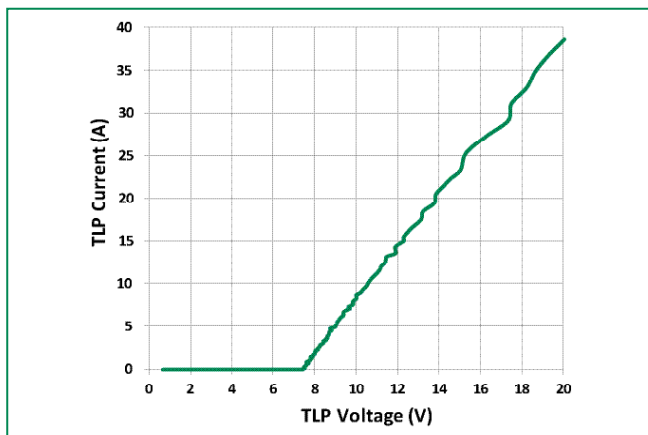
# SP1212

## 12A Discrete Unidirectional TVS Diode

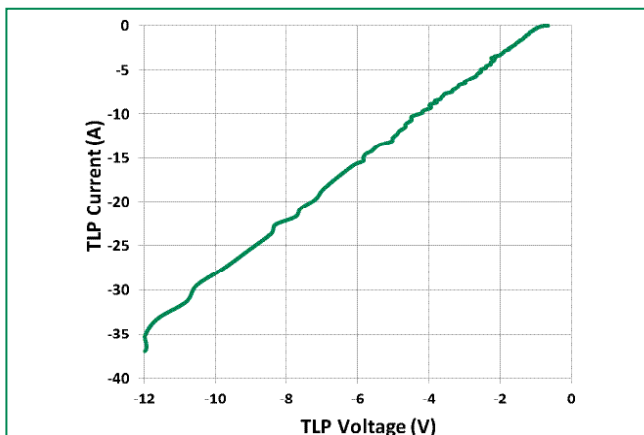
Capacitance vs. Bias



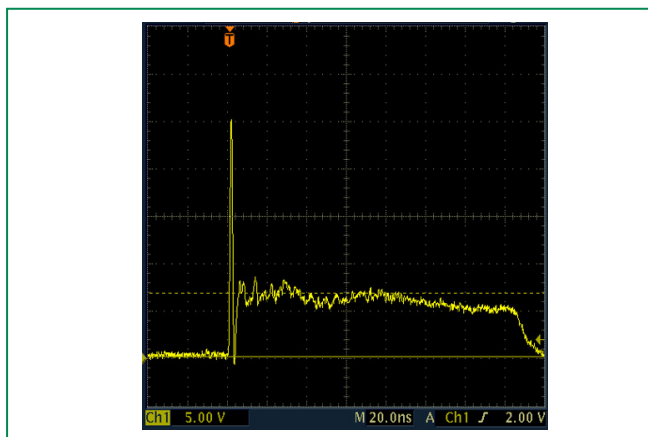
Positive Transmission Line Pulsing (TLP) Plot



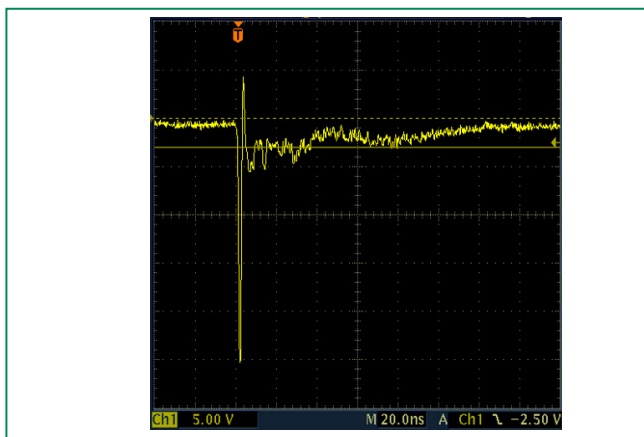
Negative Transmission Line Pulsing (TLP) Plot



IEC 61000-4-2 +8 kV Contact ESD Clamping Voltage



IEC 61000-4-2 -8 kV Contact ESD Clamping Voltage



# SP1212

## 12A Discrete Unidirectional TVS Diode

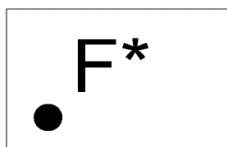
### Soldering Parameters

<b>Reflow Condition</b>		Pb – Free assembly
<b>Pre Heat</b>	- Temperature Min ( $T_{s(min)}$ )	150°C
	- Temperature Max ( $T_{s(max)}$ )	200°C
	- Time (min to max) ( $t_s$ )	60 – 180 secs
<b>Average ramp up rate (Liquidus) Temp (<math>T_L</math>) to peak</b>		3°C/second max
<b><math>T_{s(max)}</math> to <math>T_L</math> - Ramp-up Rate</b>		3°C/second max
<b>Reflow</b>	- Temperature ( $T_L$ ) (Liquidus)	217°C
	- Temperature ( $t_L$ )	60 – 150 seconds
<b>Peak Temperature (<math>T_p</math>)</b>		260 <sup>+0/-5</sup> °C
<b>Time within 5°C of actual peak Temperature (<math>t_p</math>)</b>		20 – 40 seconds
<b>Ramp-down Rate</b>		6°C/second max
<b>Time 25°C to peak Temperature (<math>T_p</math>)</b>		8 minutes Max.
<b>Do not exceed</b>		260°C

### Ordering Information

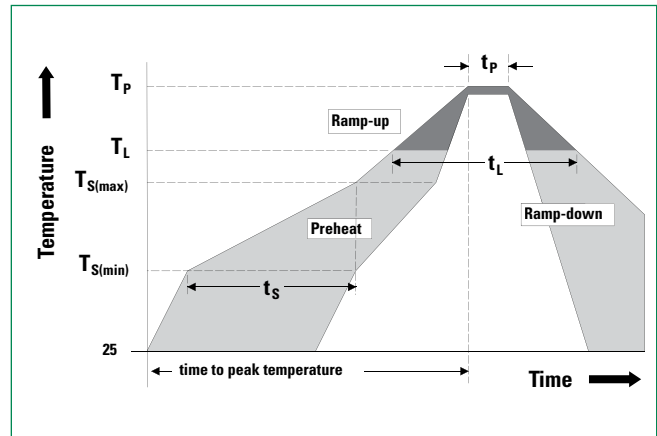
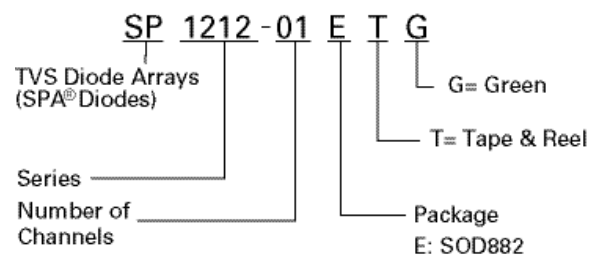
Part Number	Package	Min. Order Qty.
SP1212-01ETG	SOD882	10000

### Part Marking System



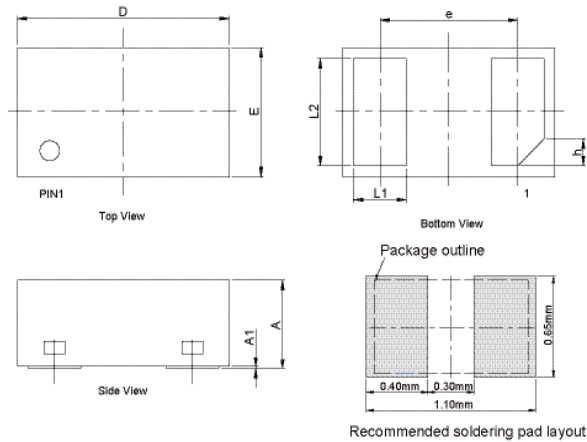
F = Part Code  
\* = Date Code

### Part Numbering System



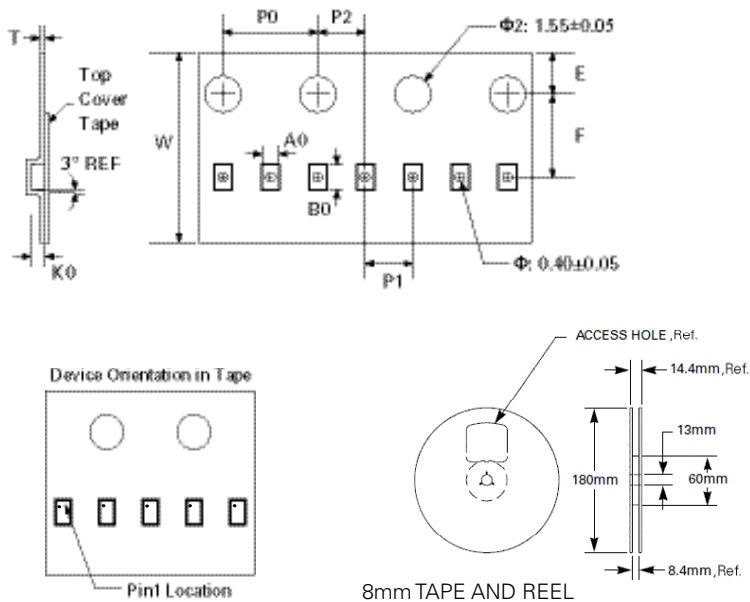
### Product Characteristics

<b>Lead Plating</b>	Matte Tin
<b>Lead Material</b>	Copper Alloy
<b>Substrate Material</b>	Silicon
<b>Body Material</b>	Molded Compound
<b>Flammability</b>	UL Recognized compound meeting flammability rating V-0

**SP1212****12A Discrete Unidirectional TVS Diode****Package Dimensions – SOD882**

Drawing#: E01-A

Symbol	Package	SOD882				
	JEDEC	MO-236				
	Millimeters			Inches		
	Min	Typ	Max	Min	Typ	Max
<b>A</b>	0.50	0.55	0.60	0.020	0.022	0.024
<b>A1</b>	0.00	0.02	0.05	0.000	0.001	0.002
<b>L1</b>	0.20	0.25	0.30	0.008	0.010	0.012
<b>L2</b>	0.45	0.50	0.55	0.018	0.020	0.022
<b>D</b>	0.90	1.00	1.10	0.035	0.039	0.043
<b>E</b>	0.50	0.60	0.70	0.020	0.024	0.028
<b>e</b>	0.65 BSC			0.026 BSC		
<b>h</b>	0.125 ( x 45° )			0.005 ( x 45° )		

**Embossed Carrier Tape & Reel Specification – SOD882**

Symbol	Tape Dimensions	
	Millimeters	
	Min	Max
<b>A0</b>	0.65	0.75
<b>B0</b>	1.10	1.20
<b>K0</b>	0.50	0.60
<b>E</b>	1.65	1.85
<b>F</b>	3.45	3.55
<b>P0</b>	3.90	4.10
<b>P1</b>	1.90	2.10
<b>P2</b>	1.95	2.05
<b>T</b>	1.95	2.05
<b>W</b>	7.90	8.10

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